

#### **Features**

- · Trench Power LV MOSFET Technology
- · High Speed Switching
- High Density Cell Design for Low R<sub>DS(on)</sub>
- Epoxy Meets UL 94 V-0 Flammability Rating
- · Moisture Sensitivity Level 1
- Halogen Free. "Green" Device (Note 1)
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

## **Maximum Ratings**

• Operating Junction Temperature Range : -55°C to +150°C

• Storage Temperature Range: -55°C to +150°C

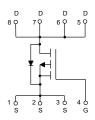
• Thermal Resistance: 3.9°C/W Junction to Case

Parameter		Symbol	Rating	Unit	
Drain-Source Voltage		V <sub>DS</sub>	-30	V	
Gate-Source Volltage		V <sub>GS</sub>	±25	V	
Continuous Drain Current	T <sub>C</sub> =25°C	. I <sub>D</sub>	-30		
	T <sub>C</sub> =100°C		-24	Α	
	T <sub>A</sub> =25°C		-11		
	T <sub>A</sub> =70°C		-9		
Pulsed Drain Current (Note 2)		I <sub>DM</sub>	-160	Α	
Avalanche Energy		E <sub>AS</sub>	72	mJ	
Total Power Dissipation		P <sub>D</sub>	32	W	

Note: 1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

2. Pulse Test: Pulse Width≤300µs,Duty cycle ≤2%.

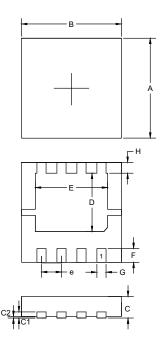
## **Internal Structure and Marking Code**





# P-CHANNEL MOSFET

### **DFN3333**



	DIMENSIONS				
DIM INCHES		HES	MM		NOTE
Dilvi	MIN	MAX	MIN	MAX	NOTE
Α	0.126	0.130	3.20	3.30	
В	0.126	0.130	3.20	3.30	
С	0.030	0.033	0.75	0.85	
C1	0.007	0.009	0.18	0.22	
C2		0.002		0.05	
D	0.071	0.079	1.80	2.00	
Е	0.087	0.098	2.20	2.50	
F	0.016	0.020	0.40	0.50	
G	0.010	0.014	0.25	0.35	
Н	0.012	0.016	0.30	0.40	
е	0.024	0.028	0.60	0.70	

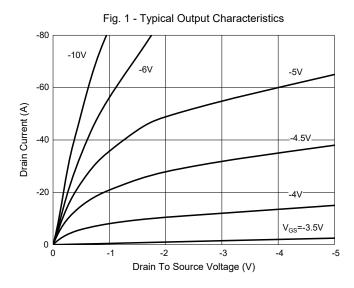


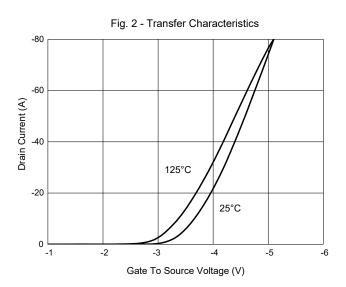
## Electrical Characteristics @ 25°C (Unless Otherwise Specified)

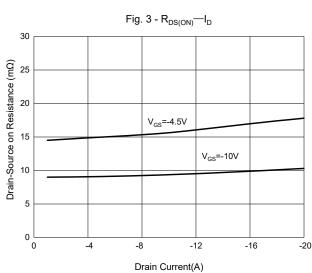
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit	
Static Characteristics							
Drain-Source Breakdown Voltage	V <sub>(BR)DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =-250μA	-30			V	
Gate-Source Leakage Current	I <sub>GSS</sub>	V <sub>DS</sub> =0V, V <sub>GS</sub> =±25V			±100	nA	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =-30V, V <sub>GS</sub> =0V			-1	μA	
Gate-Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =-250μA	-1.2	-1.8	-2.8	V	
Drain-Source On-Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =-20V, I <sub>D</sub> =-20A		8.6	13	mΩ	
		V <sub>GS</sub> =-10V, I <sub>D</sub> =-15A		9.8	15	mΩ	
		V <sub>GS</sub> =-6V, I <sub>D</sub> =-12A		12.1	22	mΩ	
		V <sub>GS</sub> =-4.5V, I <sub>D</sub> =-12A		15.5	25	mΩ	
Diode Characteristics							
Continuous Body Diode Current	Is				-30	Α	
Diode Forward Voltage	V <sub>SD</sub>	V <sub>GS</sub> =0V, I <sub>S</sub> =-20A			-1.2	V	
Dynamic Characteristics	-			1	1		
Input Capacitance	C <sub>iss</sub>			2050			
Output Capacitance	C <sub>oss</sub>	V <sub>DS</sub> =-15V,V <sub>GS</sub> =0V,f=1MHz		355		pF	
Reverse Transfer Capacitance	C <sub>rss</sub>			301			
Total Gate Charge	Qg			29.8			
Gate-Source Charge	$Q_{gs}$	V <sub>DS</sub> =-15V,V <sub>GS</sub> =-10V,I <sub>D</sub> =-20A		4.7		nC	
Gate-Drain Charge	$Q_{gd}$			10			
Turn-On Delay Time	t <sub>d(on)</sub>			14			
Turn-On Rise Time	t <sub>r</sub>	V <sub>GS</sub> =-10V,V <sub>DD</sub> =-15V, I <sub>D</sub> =-1A,		12			
Turn-Off Delay Time	t <sub>d(off)</sub>	$R_{GEN}$ =2.5 $\Omega$		26		- ns -	
Turn-Off Fall Time	t <sub>f</sub>			10			

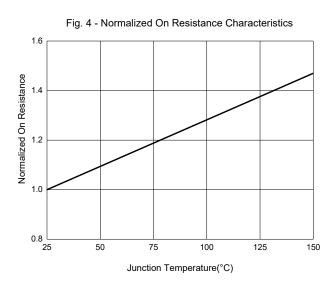


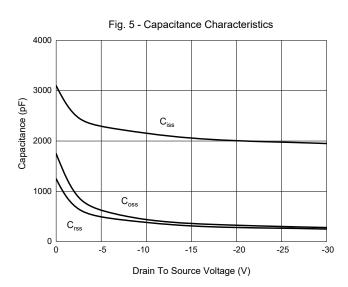
## **Curve Characteristics**

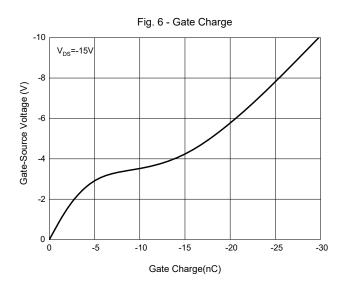














#### **Ordering Information**

Device	Packing	
Part Number-TP	Tape&Reel: 5Kpcs/Reel	

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